

3-TERMINAL 1A ADJUSTABLE VOLTAGE REGULATOR

AZ317

Pin Configuration

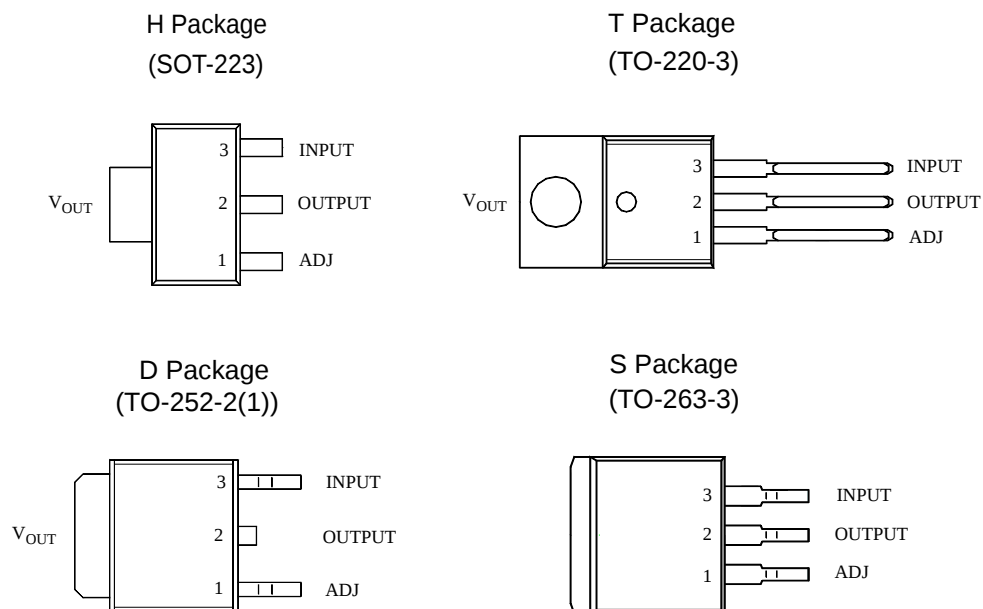


Figure 2. Pin Configuration of AZ317 (Top View)

Functional Block Diagram

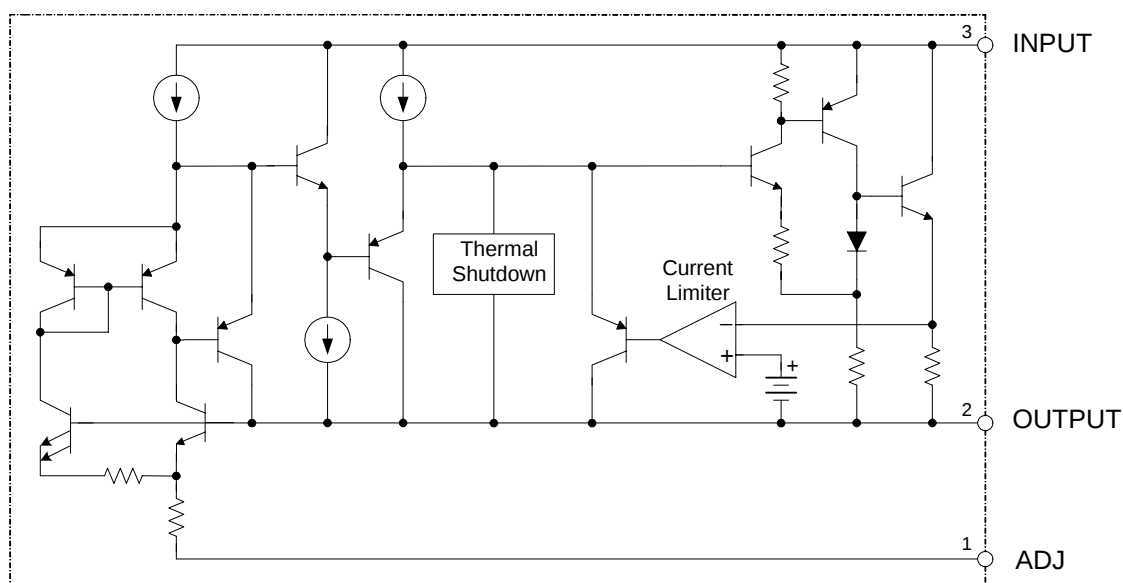
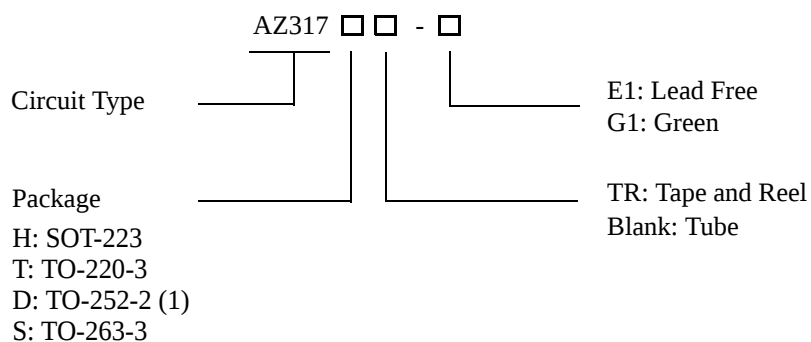


Figure 3. Functional Block Diagram of AZ317

**3-TERMINAL 1A ADJUSTABLE VOLTAGE REGULATOR****AZ317****Ordering Information**

Package	Temperature Range	Part Number		Marking ID		Packing Type
		Lead Free	Green	Lead Free	Green	
SOT-223	0 to 125°C	AZ317HTR-E1	AZ317HTR-G1	EH31A	GH31A	Tape & Reel
TO-220-3	0 to 125°C	AZ317T-E1	AZ317T-G1	AZ317T-E1	AZ317T-G1	Tube
TO-252-2 (1)	0 to 125°C	AZ317D-E1	AZ317D-G1	AZ317D-E1	AZ317D-G1	Tube
		AZ317DTR-E1	AZ317DTR-G1	AZ317D-E1	AZ317D-G1	Tape & Reel
TO-263-3	0 to 125°C	AZ317S-E1	AZ317S-G1	AZ317S-E1	AZ317S-G1	Tube
		AZ317STR-E1	AZ317STR-G1	AZ317S-E1	AZ317S-G1	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.

**3-TERMINAL 1A ADJUSTABLE VOLTAGE REGULATOR****AZ317****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Min	Max	Unit
Input Voltage	V_{IN}		20	V
Maximum Junction Temperature	T_J		150	°C
Storage Temperature	T_S	-65	150	°C
Lead Temperature (Soldering, 10sec)	T_{LEAD}		300	°C
ESD (Human Body Model)	ESD		4000	V

Note1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Input Voltage	V_{IN}	$V_{OUT}+2$	15	V
Operating Junction Temperature Range	T_J	0	125	°C

**3-TERMINAL 1A ADJUSTABLE VOLTAGE REGULATOR****AZ317****Electrical Characteristics**(Typicals and limits apply for $T_J = 25^\circ\text{C}$, $P \leq$ Maximum Power Dissipation unless otherwise specified.)(Note 2)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reference Voltage	V_{REF}	$10\text{mA} \leq I_{OUT} \leq 1\text{A}$, $3\text{V} \leq (V_{IN} - V_{OUT}) \leq 10\text{V}$	1.20	1.25	1.30	V
Line Regulation	S_V	$I_{OUT} \leq 20\text{mA}$, $3\text{V} \leq V_{IN} - V_{OUT} \leq 10\text{V}$		0.01	0.04	%/V
Load Regulation	S_i	$V_{IN} - V_{OUT} = 2\text{V}$, $10\text{mA} \leq I_{OUT} \leq 1\text{A}$		0.2	0.4	%
Thermal Regulation		20ms Pulse		0.04	0.07	%/W
Dropout Voltage	ΔV	$I_{OUT} = 1\text{A}$		1.2	1.3	V
Current Limit	I_{LIMIT}	$(V_{IN} - V_{OUT}) = 2\text{V}$	1.2	1.5	1.8	A
Adjust Pin Current				50	100	μA
Adjust Pin Current Change		$1.4\text{V} \leq (V_{IN} - V_{OUT}) \leq 10\text{V}$, $10\text{mA} \leq I_{OUT} \leq 1\text{A}$		0.2	5	μA
Minimum Load Current		$3\text{V} \leq (V_{IN} - V_{OUT}) \leq 15\text{V}$		3.5	10	mA
Ripple Rejection		$f = 120\text{Hz}$, $C_{OUT} = 1\mu\text{F}$ Tantalum, $(V_{IN} - V_{OUT}) = 3\text{V}$, $I_{OUT} = 1\text{A}$	60	75		dB
Temperature Stability				1		%
Long -Term Stability		$T_A = 125^\circ\text{C}$, 1000hrs		0.3		%
RMS Output Noise (% of V_{OUT})		$T_A = 25^\circ\text{C}$, $10\text{Hz} \leq f \leq 10\text{kHz}$		0.003		%
Thermal Resistance, Junction to Case		SOT-223 TO-252 TO-220 TO-263		15 10 4.5 4		$^\circ\text{C/W}$
Thermal Shutdown		Junction Temperature		150		$^\circ\text{C}$
Thermal Shutdown Hysteresis				25		$^\circ\text{C}$

Note 2: Maximum Power Dissipation is Package Type and Case Temperature dependent. Please see Figure 12.

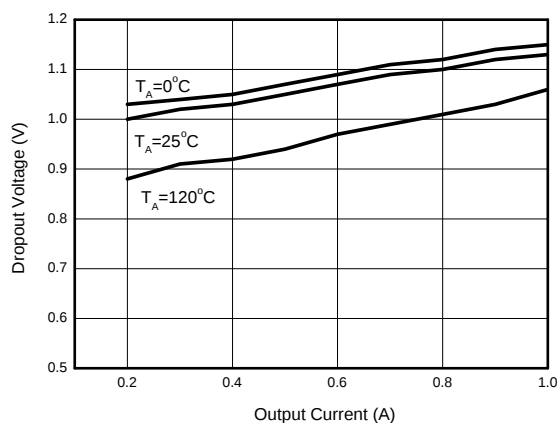
**3-TERMINAL 1A ADJUSTABLE VOLTAGE REGULATOR****AZ317****Typical Performance Characteristics**

Figure 5. Dropout Voltage vs. Output Current

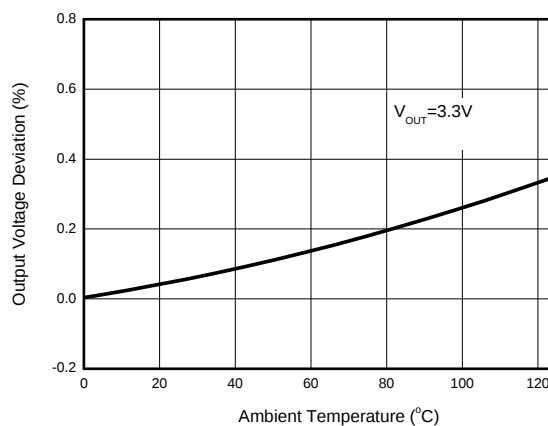


Figure 6. Load Regulation vs. Temperature

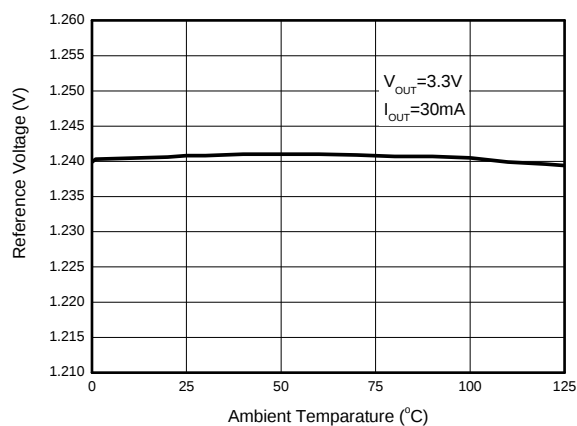


Figure 7. Reference Voltage vs. Temperature

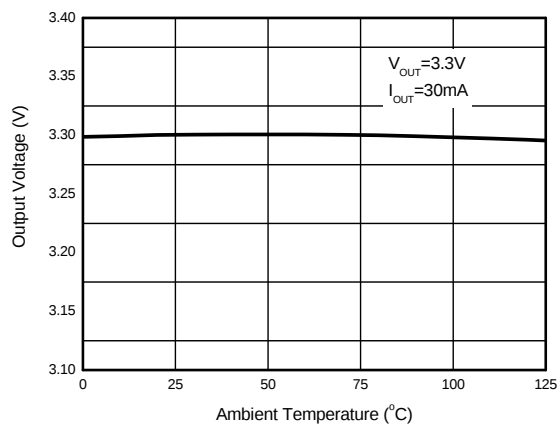


Figure 8. Output Voltage vs. Temperature

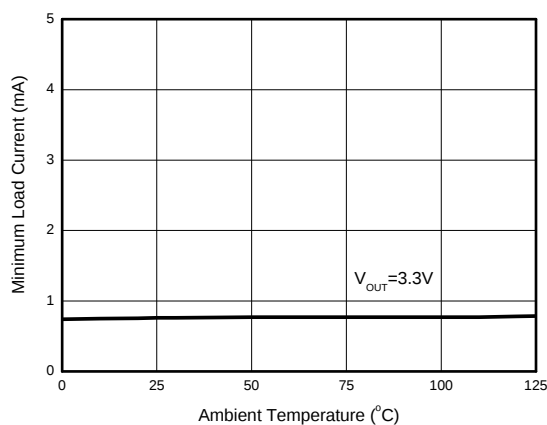
**3-TERMINAL 1A ADJUSTABLE VOLTAGE REGULATOR****AZ317****Typical Performance Characteristics (Continued)**

Figure 9. Minimum Load Current vs. Temperature

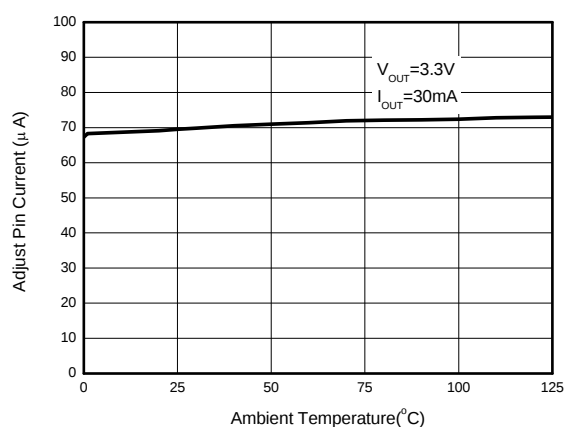


Figure 10. Adjust Pin Current vs. Temperature

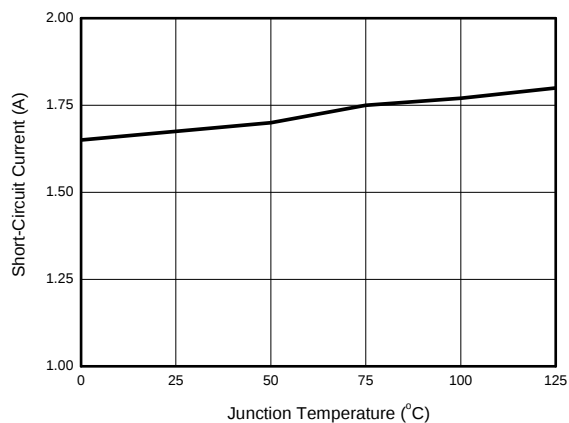


Figure 11. Short-Circuit Current vs. Temperature

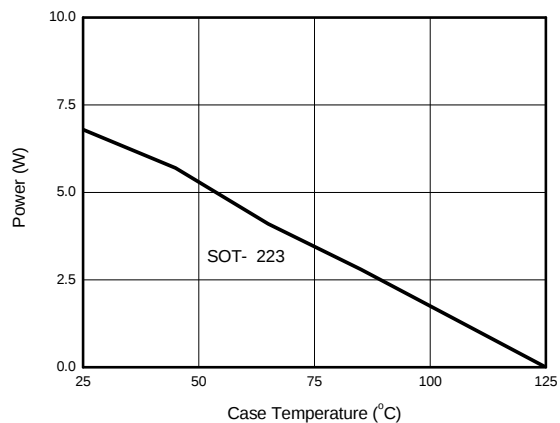


Figure 12. Maximum Power Dissipation

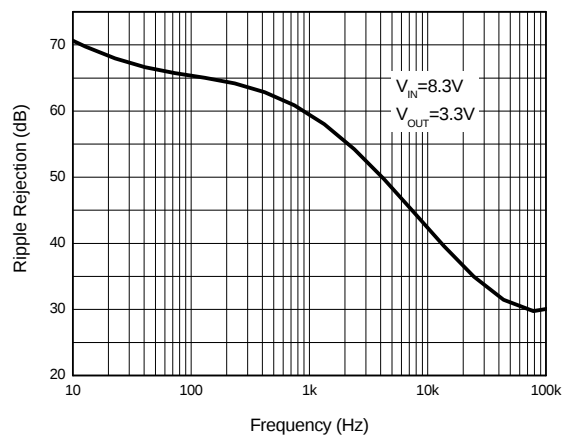
**3-TERMINAL 1A ADJUSTABLE VOLTAGE REGULATOR****AZ317****Typical Performance Characteristics (Continued)**

Figure 13. Ripple Rejection vs. Frequency

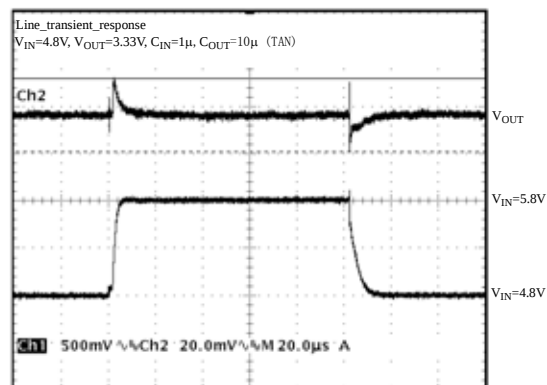


Figure 14. Line Transient Response

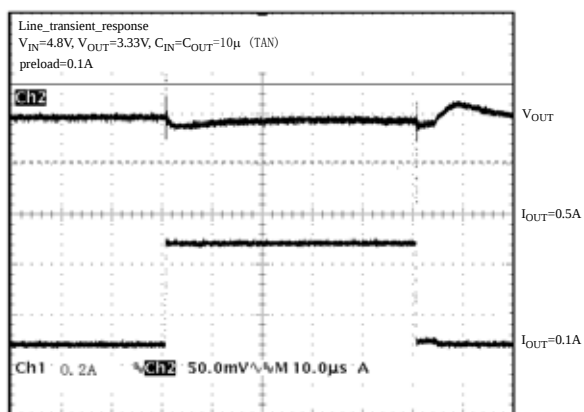
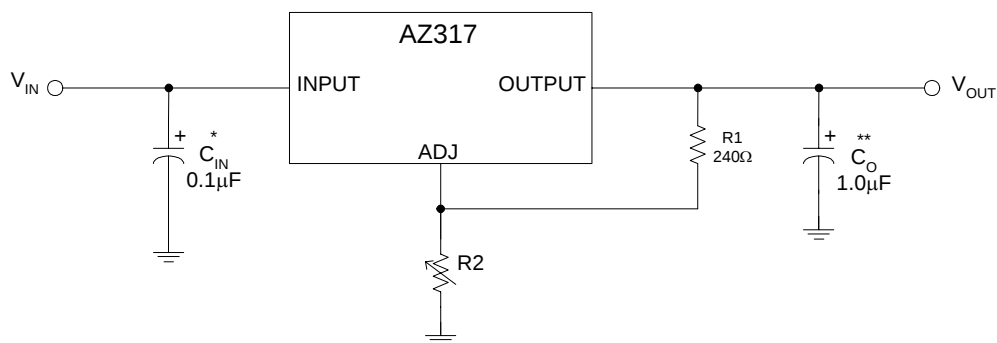


Figure 15. Load Transient Response

**3-TERMINAL 1A ADJUSTABLE VOLTAGE REGULATOR****AZ317****Typical Application**

* = C_{IN} is required if the regulator is located near power supply filter.

**= C_O is needed for stability and it improves transient response.

$$V_{OUT} = V_{REF} \times (1 + R2/R1) + I_{ADJ} \times R2$$

Since I_{ADJ} is controlled to less than 100µA, the error associated with this term is negligible in most applications.

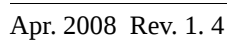
Figure 4. Typical Application of AZ317



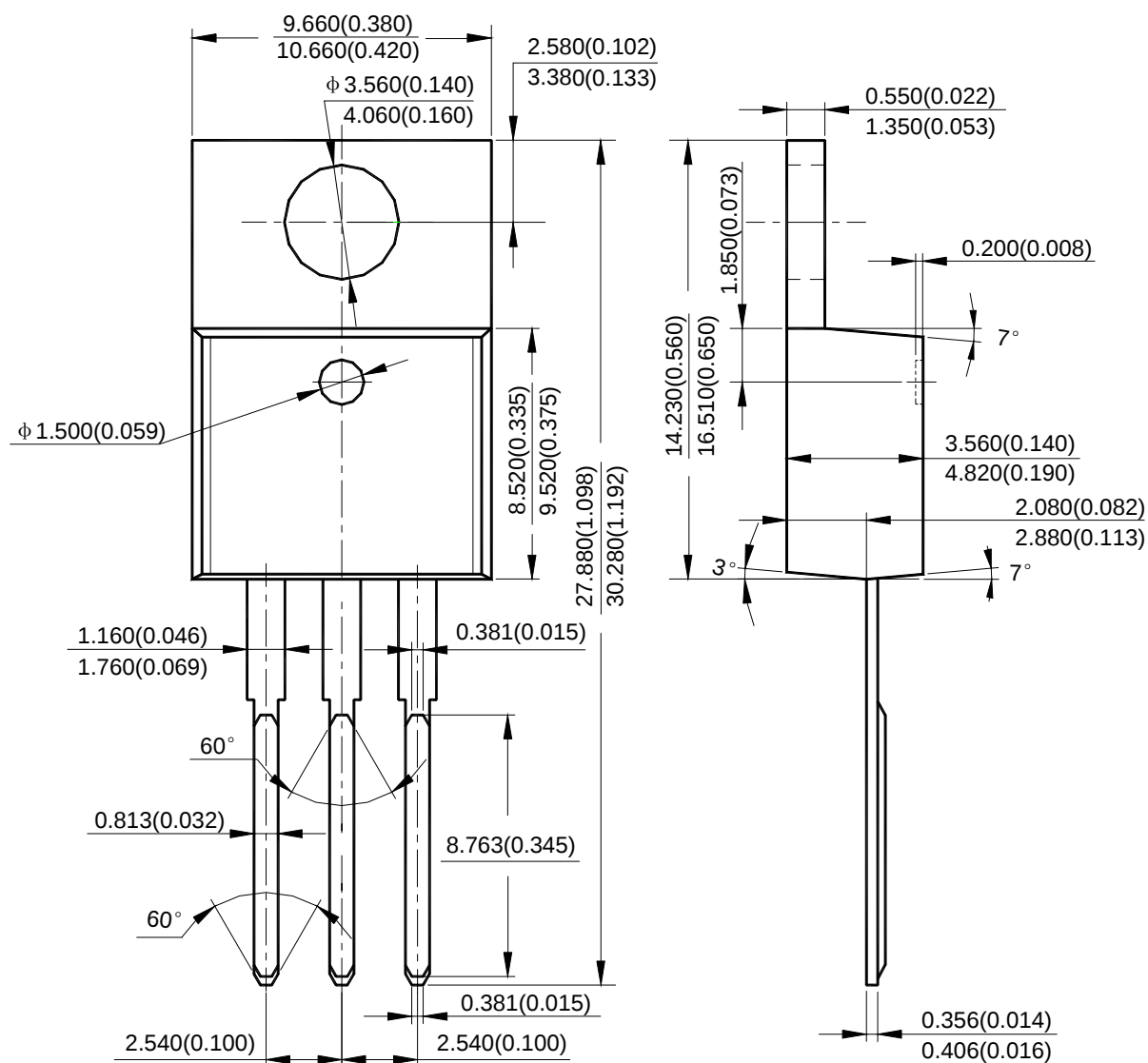
AZ317

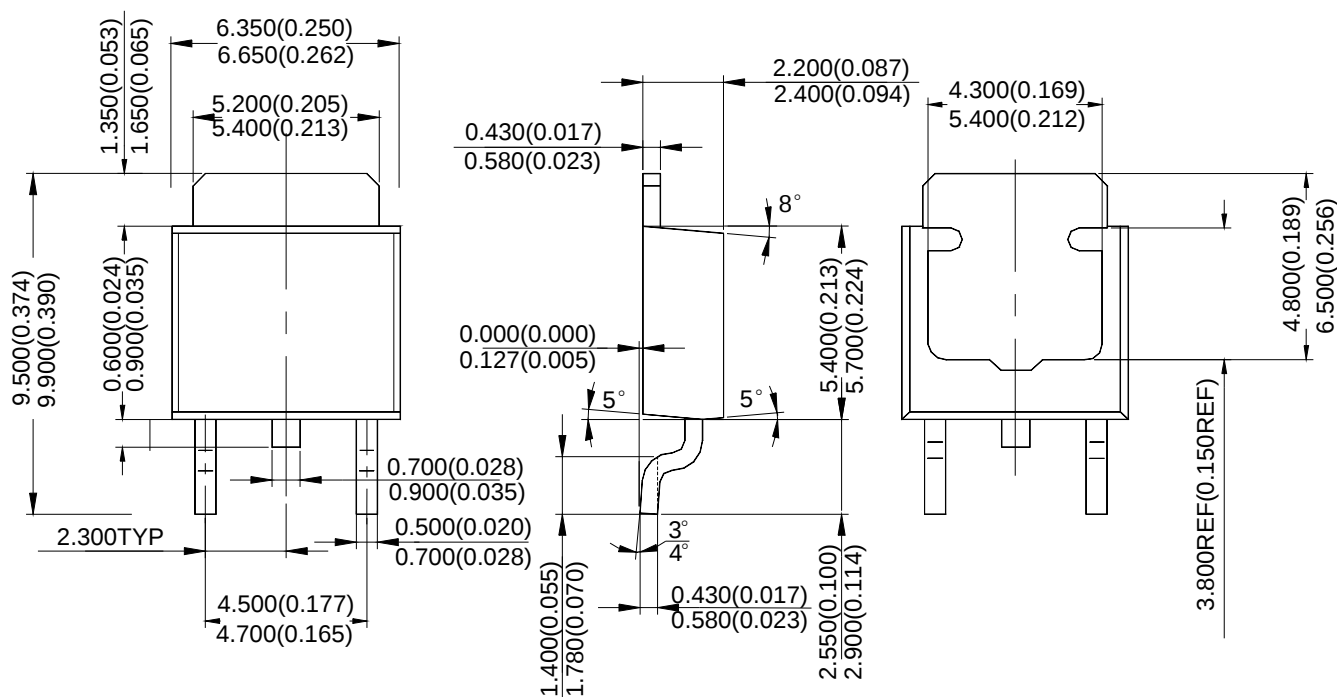
SOT-223

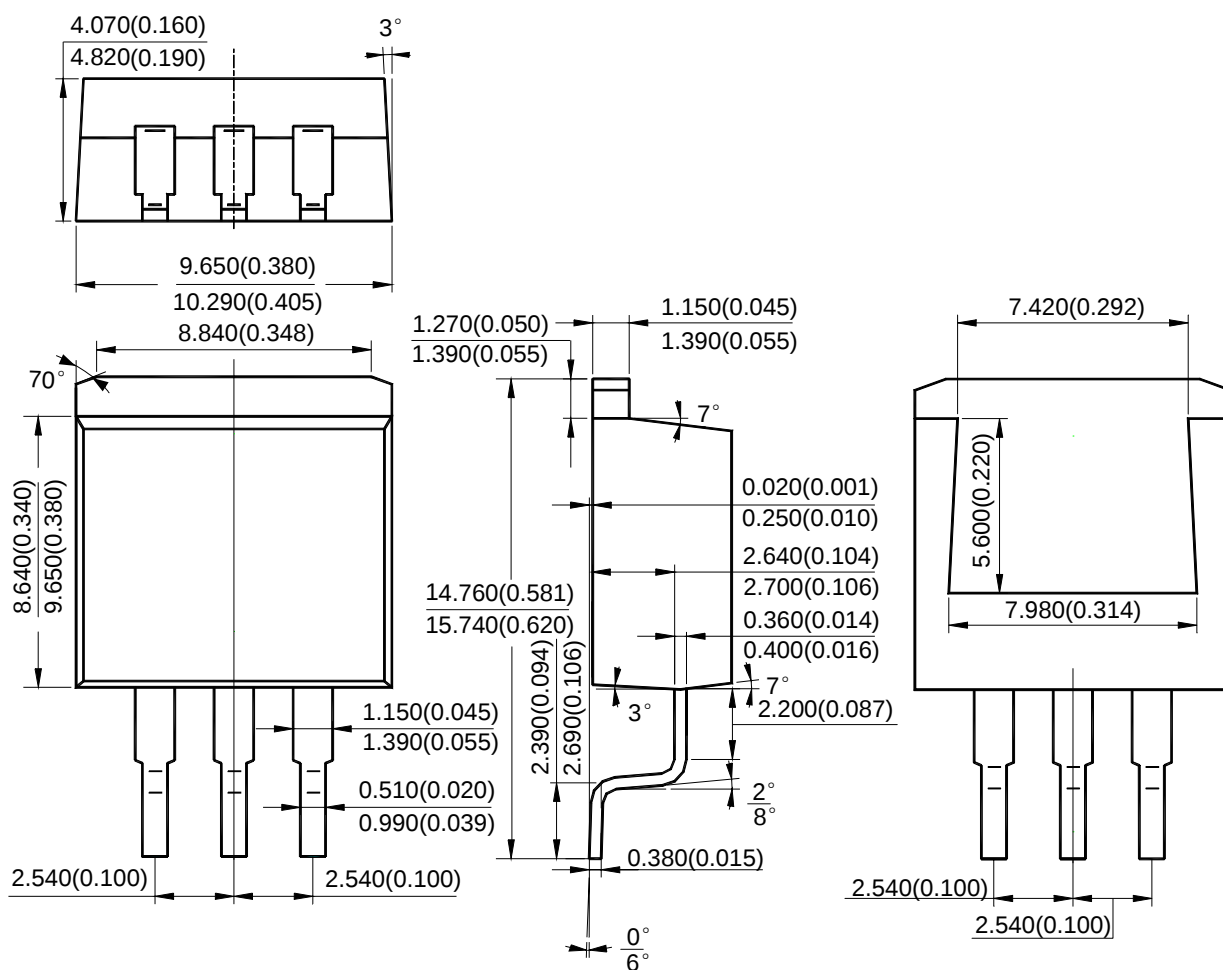
Unit: mm(inch)



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**3-TERMINAL 1A ADJUSTABLE VOLTAGE REGULATOR****AZ317****Mechanical Dimensions (Continued)****TO-220-3****Unit: mm(inch)**

**3-TERMINAL 1A ADJUSTABLE VOLTAGE REGULATOR****AZ317****Mechanical Dimensions (Continued)****TO-252-2(1)****Unit: mm(inch)**

**3-TERMINAL 1A ADJUSTABLE VOLTAGE REGULATOR****AZ317****Mechanical Dimensions (Continued)****TO-263-3****Unit: mm(inch)**



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